



256-Tap, Nonvolatile, SPI-Interface, Digital Potentiometers

Features

Pin Configuration

Ordering Information/Selector Guide

256-Tap, Nonvolatile, SPI-Interface, Digital Potentiometers

ABSOLUTE MAXIMUM RATINGS

V _{DD} to GND	-0.3V to +6.0V
All Other Pins to GND.....	-0.3V to (V _{DD} + 0.3V)
Maximum Continuous Current into H, L, and W	
MAX5422.....	±1.3mA
MAX5423.....	±0.6mA
MAX5424.....	±0.3mA

Continuous Power Dissipation (T _A = +70°C)	
8-Pin TDFN (derate 24.4mW/°C above +70°C)	1951mW
Operating Temperature Range	-40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	-60°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V_{DD} = +2.7V to +5.25V, H = V_{DD}, L = GND, T_A = -40°C to +85°C. Typical values are at V_{DD} = +5.0V, T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
DC PERFORMANCE (VOLTAGE-DIVIDER MODE)							
Resolution	N		256			Taps	
Integral Nonlinearity	INL	(Note 1)		±0.5			LSB
Differential Nonlinearity	DNL	(Note 1)		±0.5			LSB
End-to-End Resistance Temperature Coefficient	TC _R			35			ppm/°C
Ratiometric Resistance Temperature Coefficient				5			ppm/°C
Full-Scale Error		MAX5422		-0.6			LSB
		MAX5423		-0.3			
		MAX5424		-0.15			
Zero-Scale Error		MAX5422		0.7			LSB
		MAX5423		0.35			
		MAX5424		0.18			
DC PERFORMANCE (VARIABLE-RESISTOR MODE)							
Integral Nonlinearity (Note 2)	INL	V _{DD} = 3V		±3.0			LSB
		V _{DD} = 5V		±1.5			
Differential Nonlinearity (Note 2)	DNL	V _{DD} = 3V, MAX5422, -40°C ≤ T _A ≤ +85°C, guaranteed monotonic	-1.0	+2.0			LSB
		V _{DD} = 3V, MAX5422, 0°C ≤ T _A ≤ +85°C, guaranteed monotonic	-1.0	+1.2			
		V _{DD} = 3V, MAX5423		±1.0			
		V _{DD} = 3V, MAX5424		±1.0			
		V _{DD} = 5V		±1.0			
DC PERFORMANCE (RESISTOR CHARACTERISTICS)							
Wiper Resistance	R _W	V _{DD} = 3V to 5.25V (Note 3)		325	675	Ω	
Wiper Capacitance	C _W			10		pF	
End-to-End Resistance		MAX5422	37.5	50	62.5	kΩ	
		MAX5423	75	100	125		
		MAX5424	150	200	250		

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MAX5422/MAX5423/MAX5424

ELECTRICAL CHARACTERISTICS (continued)

(V_{DD} = +2.7V to +5.25V, H = V_{DD} , L = GND, T_A = -40°C to +85°C. Typical values are at V_{DD} = +5.0V, T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
DIGITAL INPUTS ($\overline{CS}$, DIN, SCLK)						
Input High Voltage (Note 4)	V_{IH}	$V_{DD} = 3.4V$ to 5.25V	2.4		V	
		$V_{DD} < 3.4V$	0.7 x V_{DD}			
Input Low Voltage	V_{IL}	$V_{DD} = 2.7V$ to 5.25V (Note 4)	0.8		V	
Input Leakage Current	I_{IN}		±0.1	±1	μA	
Input Capacitance	C_{IN}		5		pF	
DYNAMIC CHARACTERISTICS						
Wiper -3dB Bandwidth (Note 5)		MAX5422	100		kHz	
		MAX5423	50			
		MAX5424	25			
NONVOLATILE MEMORY RELIABILITY						
Data Retention		$T_A = +85^{\circ}C$	50		Years	
Endurance		$T_A = +25^{\circ}C$	200,000		Stores	
		$T_A = +85^{\circ}C$	50,000			
POWER SUPPLY						
Supply Voltage	V_{DD}		2.70	5.25	V	
Standby Current	I_{DD}	Digital inputs = V_{DD} or GND, $T_A = +25^{\circ}C$	0.5	1	μA	
Programming Current	I_{PG}	During nonvolatile write to memory; digital inputs = V_{DD} or GND (Note 6)	200	400	μA	

TIMING CHARACTERISTICS

(V_{DD} = +2.7V to +5.25V, H = V_{DD} , L = GND, T_A = -40°C to +85°C. Typical values are at V_{DD} = +5.0V, T_A = +25°C, unless otherwise noted. See Figure 1.) (Note 7)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
ANALOG SECTION						
Wiper Settling Time (Note 8)	ts	MAX5422	400			ns
		MAX5423	600			
		MAX5424	1000			
DIGITAL SECTION						
SCLK Frequency	fSCLK		5			MHz
SCLK Clock Period	tCP		200			ns
SCLK Pulse-Width High	tCH		80			ns
SCLK Pulse-Width Low	tCL		80			ns
$\overline{CS}$ Fall to SCLK Rise Setup	tCSS		80			ns
SCLK Rise to $\overline{CS}$ Rise Hold	tCSH		0			ns
DIN to SCLK Setup	tDS		50			ns

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TIMING CHARACTERISTICS (continued)

($V_{DD} = +2.7V$ to $+5.25V$, $H = V_{DD}$, $L = GND$, $T_A = -40^\circ C$ to $+85^\circ C$. Typical values are at $V_{DD} = +5.0V$, $T_A = +25^\circ C$, unless otherwise noted. See Figure 1.) (Note 7)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
DIN Hold after SCLK	t_{DH}		0			ns
SCLK Rise to $\overline{CS}$ Fall Delay	t_{CS0}		20			ns
$\overline{CS}$ Rise to SCLK Rise Hold	t_{CS1}		80			ns
$\overline{CS}$ Pulse-Width High	t_{CSW}		200			ns
Write NV Register Busy Time	t_{BUSY}				12	ms

Note 1: The DNL and INL are measured with the potentiometer configured as a voltage-divider with $H = V_{DD}$ and $L = GND$. The wiper terminal is unloaded and measured with a high-input-impedance voltmeter.

Note 2: The DNL and INL are measured with the potentiometer configured as a variable resistor. H is unconnected and $L = GND$. For the 5V condition, the wiper terminal is driven with a source current of $80\mu A$ for the $50k\Omega$ configuration, $40\mu A$ for the $100k\Omega$ configuration, and $20\mu A$ for the $200k\Omega$ configuration. For the 3V condition, the wiper terminal is driven with a source current of $40\mu A$ for the $50k\Omega$ configuration, $20\mu A$ for the $100k\Omega$, and $10\mu A$ for the $200k\Omega$ configuration.

Note 3: The wiper resistance is measured using the source currents given in Note 2. For operation to $V_{DD} = 2.7V$, see Maximum Wiper Resistance vs. Temperature in the *Typical Operating Characteristics*.

Note 4: The device draws higher supply current when the digital inputs are driven with voltages between ($V_{DD} - 0.5V$) and ($GND + 0.5V$). See Supply Current vs. Digital Input Voltage in the *Typical Operating Characteristics*.

Note 5: Wiper at midscale with a $10pF$ load (DC measurement). $L = GND$; an AC source is applied to H ; and the W output is measured. A 3dB bandwidth occurs when the AC W/H value is 3dB lower than the DC W/H value.

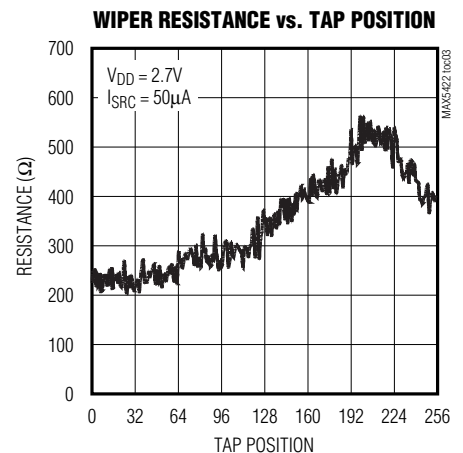
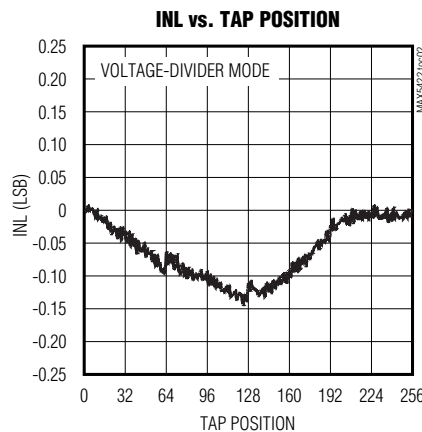
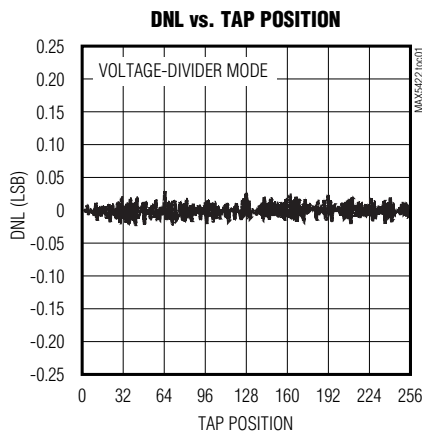
Note 6: The programming current operates only during power-up and NV writes.

Note 7: Digital timing is guaranteed by design and characterization, and is not production tested.

Note 8: Wiper-settling time is the worst-case 0% to 50% rise-time measured between consecutive wiper positions. $H = V_{DD}$, $L = GND$, and the wiper terminal is unloaded and measured with a $10pF$ oscilloscope probe.

Typical Operating Characteristics

($V_{DD} = 5.0V$, $T_A = +25^\circ C$, unless otherwise noted.)

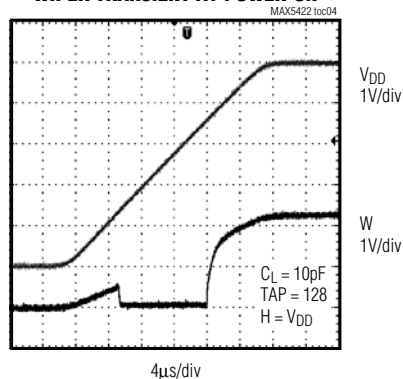


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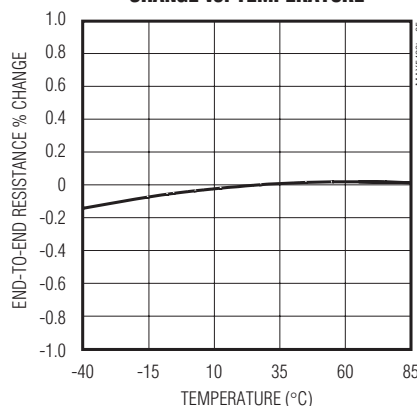
Typical Operating Characteristics (continued)

($V_{DD} = 5.0V$, $T_A = +25^\circ C$, unless otherwise noted.)

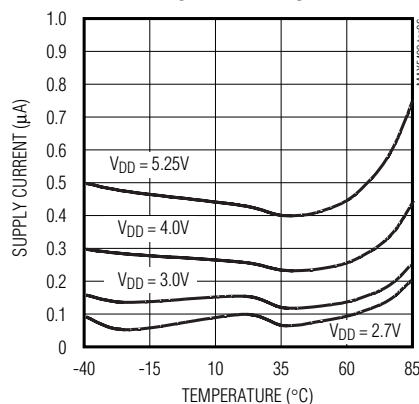
WIPER TRANSIENT AT POWER-ON



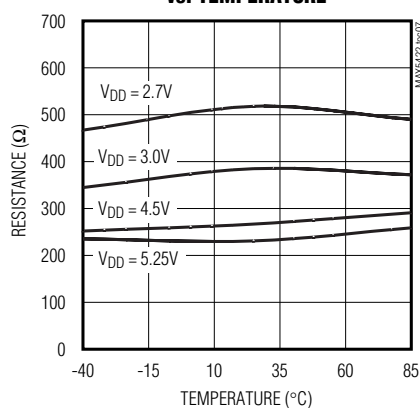
END-TO-END RESISTANCE % CHANGE vs. TEMPERATURE



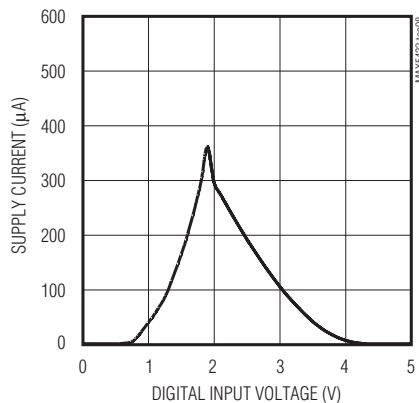
STANDBY SUPPLY CURRENT vs. TEMPERATURE



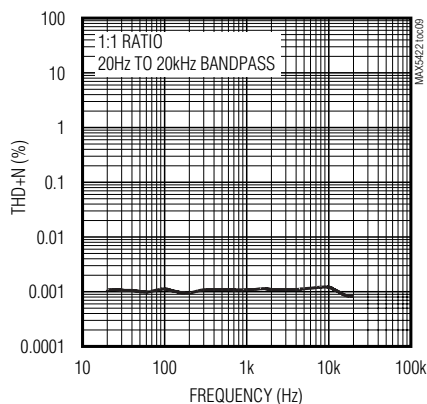
MAXIMUM WIPER RESISTANCE vs. TEMPERATURE



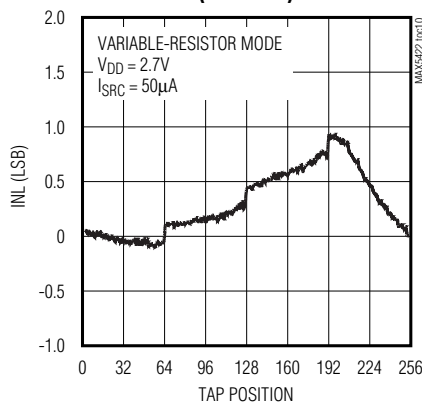
SUPPLY CURRENT vs. DIGITAL INPUT VOLTAGE



THD+N RESPONSE



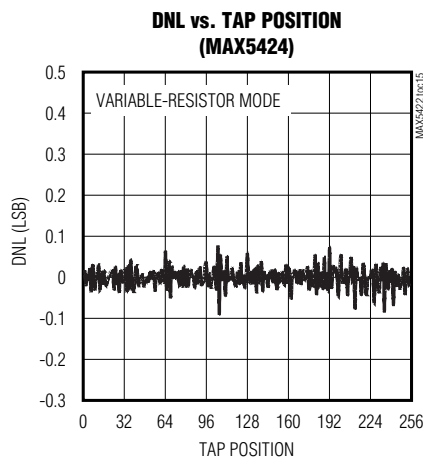
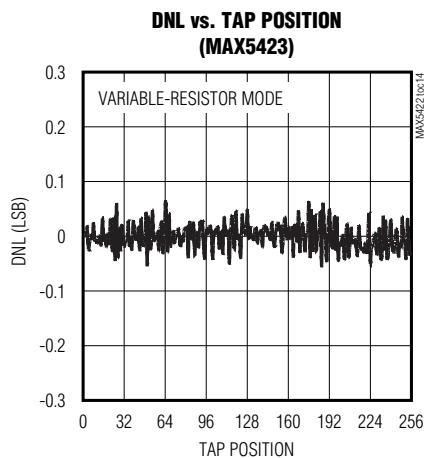
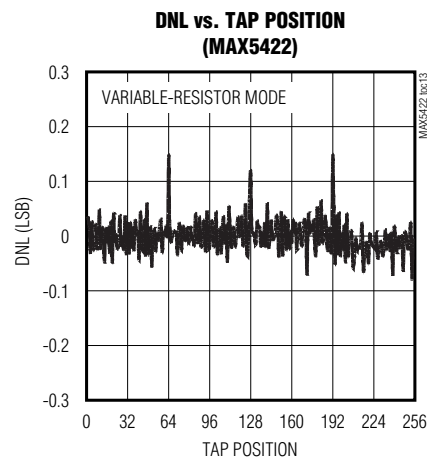
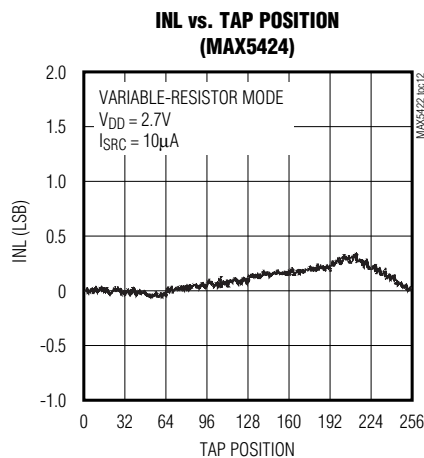
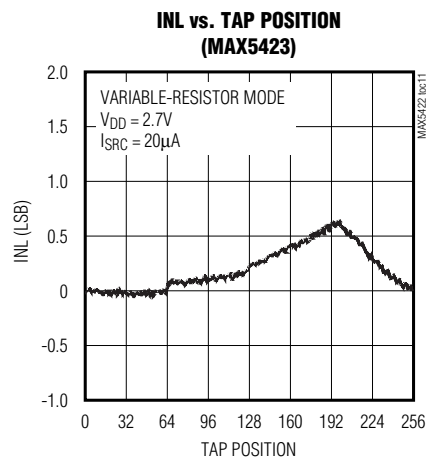
INL vs. TAP POSITION (MAX5422)



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Typical Operating Characteristics (continued)

($V_{DD} = 5.0V$, $T_A = +25^\circ C$, unless otherwise noted.)



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Pin Description

PIN	NAME	FUNCTION
1	V _{DD}	Power-Supply Input. Bypass V _{DD} with a 0.1μF capacitor from V _{DD} to GND.
2	SCLK	Serial-Interface Clock Input
3	DIN	Serial-Interface Data Input
4	$\overline{CS}$	Active-Low Digital-Input Chip Select
5	GND	Ground
6	L	Low Terminal. The voltage at L can be greater than or less than the voltage at H. Current can flow into or out of L.
7	W	Wiper Terminal
8	H	High Terminal. The voltage at H can be greater than or less than the voltage at L. Current can flow into or out of H.
—	EP	Exposed Pad. The exposed pad is not internally connected. Connect to GND or leave floating.

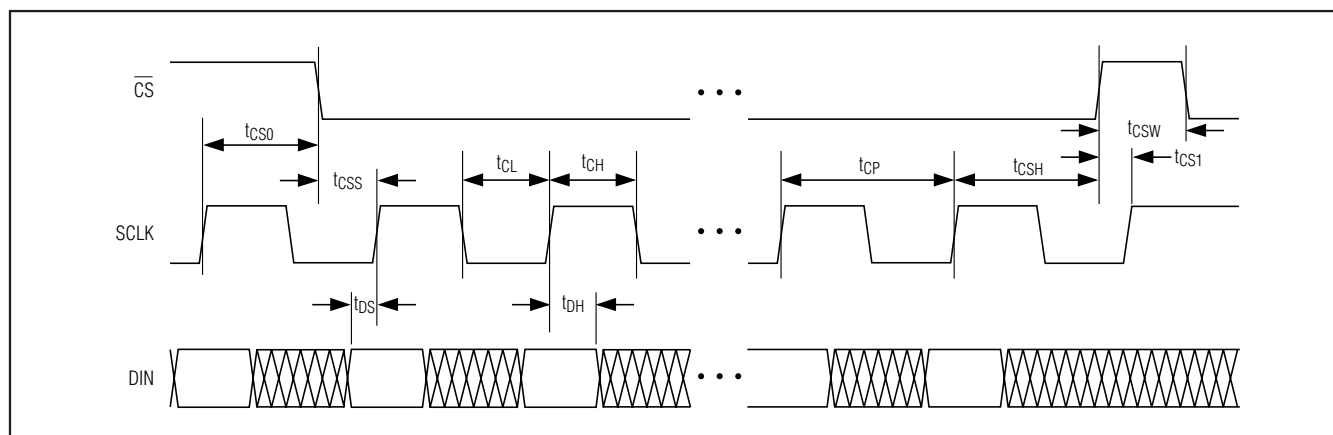


Figure 1. Digital Interface and Timing Diagram

Detailed Description

The MAX5422/MAX5423/MAX5424 contain a resistor array with 255 resistive elements. The MAX5422 has a total end-to-end resistance of 50kΩ; the MAX5423 has an end-to-end resistance of 100kΩ; and the MAX5424 has an end-to-end resistance of 200kΩ. The MAX5422/MAX5423/MAX5424 allow access to the high, low, and wiper terminals for a standard voltage-divider configuration. H, L, and W can be connected in any desired configuration as long as their voltages fall between GND and V_{DD}.

A simple, 3-wire, SPI serial interface moves the wiper among the 256 tap points. The nonvolatile memory stores the wiper position and recalls the stored wiper position upon power-up. The nonvolatile memory is guaranteed for 50 years for wiper data retention and up to 200,000 wiper store cycles.

Analog Circuitry

The MAX5422/MAX5423/MAX5424 consist of a resistor array with 255 resistive elements; 256 tap points are accessible to the wiper, W, along the resistor string between H and L. Select the wiper tap point by programming the potentiometer through the 3-wire (SPI) interface. Eight data bits, and a control byte program the wiper position. The H and L terminals of the MAX5422/MAX5423/MAX5424 are similar to the two end terminals of a mechanical potentiometer. The MAX5422/MAX5423/MAX5424 feature power-on reset circuitry that loads the wiper position from the non-volatile memory at power-up.

Digital Interface

The MAX5422/MAX5423/MAX5424 use a 3-wire, SPI-compatible, serial data interface (Figure 1 and 2). This write-only interface contains three inputs: chip-select

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($\overline{CS}$), data clock (SCLK), and data in (DIN). Drive $\overline{CS}$ low to enable the serial interface and clock data synchronously into the shift register on each SCLK rising edge.

The WRITE commands (C1, C0 = 00 or 01) require 16 clock cycles to clock in the command and data (Figure 2a). The COPY commands (C1, C0 = 10, 11) can use either eight clock cycles to transfer the command bits (Figure 2b) or 16 clock cycles with 8 data bits that are disregarded by the device (Figure 2a).

After loading data into the shift register, drive $\overline{CS}$ high to latch the data into the appropriate potentiometer control register and disable the serial interface. Keep $\overline{CS}$ low during the entire serial-data stream to avoid corruption of the data.

The serial-data timing for the potentiometer is shown in Figures 1 and 2.

Table 1. Register Map

CLOCK EDGE	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
Bit name	—	—	C1	C0	—	—	—	—	D7	D6	D5	D4	D3	D2	D1	D0
Write wiper register	0	0	0	0	0	0	0	0	D7	D6	D5	D4	D3	D2	D1	D0
Write NV register	0	0	0	1	0	0	0	0	D7	D6	D5	D4	D3	D2	D1	D0
Copy wiper register to NV register	0	0	1	0	0	0	0	0	—	—	—	—	—	—	—	—
Copy NV register to wiper register	0	0	1	1	0	0	0	0	—	—	—	—	—	—	—	—

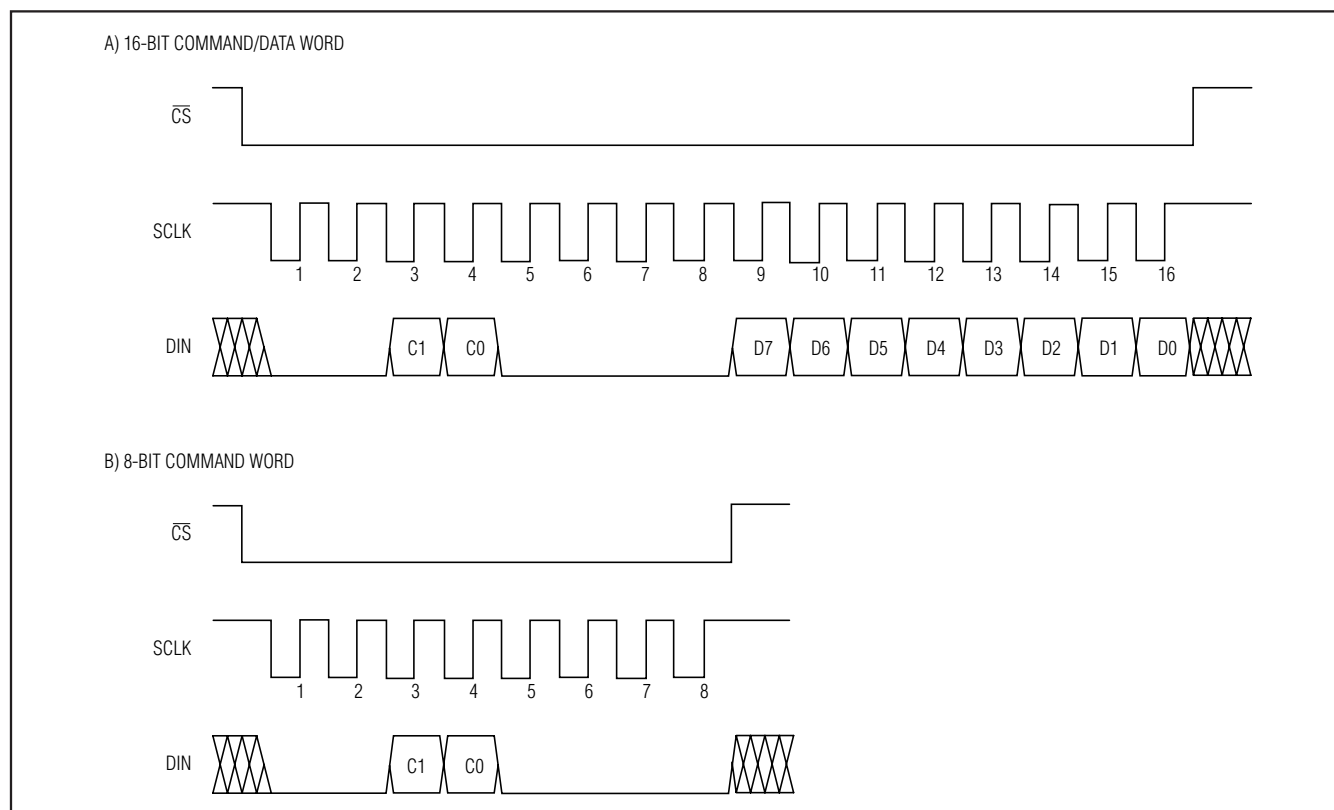


Figure 2. Digital-Interface Format

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Write Wiper Register

Data written to this register (C1, C0 = 00) controls the wiper positions. The 8 data bits (D7 to D0) indicate the position of the wiper. For example, if DIN = 0000 0000, the wiper moves to the position closest to L. If DIN = 1111 1111, the wiper moves closest to H.

This command writes data to the volatile random access memory (RAM), leaving the NV registers unchanged. When the device powers up, the data stored in the NV registers transfers to the volatile wiper register, moving the wiper to the stored position.

Write NV Register

The “write NV register” command (C1, C0 = 01) stores the position of the wipers to the NV registers for use at power-up. Alternatively, the “copy wiper register to NV register” command writes to the NV register. Writing to the NV registers, does not affect the position of the wipers.

Copy Wiper Register to NV Register

The “copy wiper register to NV register” command (C1, C0 = 10) stores the current position of the wiper to the NV register for use at power-up.

Copy NV Register to Wiper Register

The “copy NV register to wiper register” (C1, C0 = 11) restores the wiper position to the current value stored in the NV register.

Standby Mode

The MAX5422/MAX5423/MAX5424 feature a low-power standby mode. When the device is not being pro-

grammed, it enters into standby mode and supply current drops to 0.5μA (typ).

Nonvolatile Memory

The internal EEPROM consists of a nonvolatile register that retains the last value stored prior to power-down. The nonvolatile register is programmed to midscale at the factory. The nonvolatile memory is guaranteed for 50 years for wiper data retention and up to 200,000 wiper write cycles.

Power-Up

Upon power-up, the MAX5422/MAX5423/MAX5424 load the data stored in the nonvolatile wiper register into the volatile wiper register, updating the wiper position with the data stored in the nonvolatile wiper register. This initialization period takes 10μs.

Applications Information

The MAX5422/MAX5423/MAX5424 are intended for circuits requiring digitally controlled adjustable resistance, such as LCD contrast control (where voltage biasing adjusts the display contrast), or programmable filters with adjustable gain and/or cutoff frequency.

Positive LCD Bias Control

Figures 3 and 4 show an application where a voltage-divider or variable resistor is used to make an adjustable, positive LCD-bias voltage. The op amp provides buffering and gain to the resistor-divider network made by the potentiometer (Figure 3) or to a fixed resistor and a variable resistor (see Figure 4).

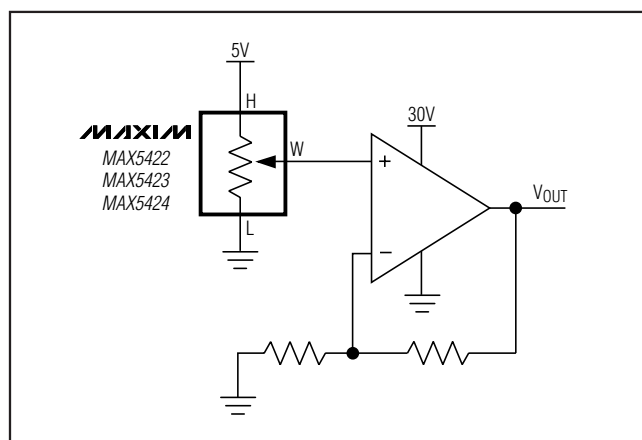


Figure 3. Positive LCD-Bias Control Using a Voltage-Divider

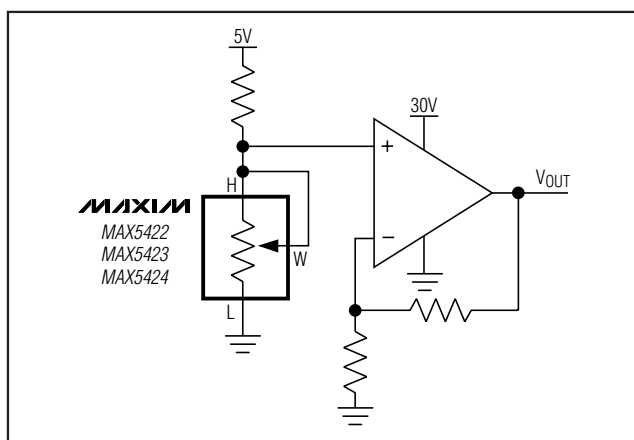


Figure 4. Positive LCD-Bias Control Using a Variable Resistor

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Programmable Filter

Figure 5 shows the configuration for a 1st-order programmable filter. The gain of the filter is adjusted by R2, and the cutoff frequency is adjusted by R3. Use the following equations to calculate the DC gain (G) and the 3dB cutoff frequency (f_C):

$$G = 1 + \frac{R1}{R2}$$

$$f_C = \frac{1}{2\pi \times R3 \times C}$$

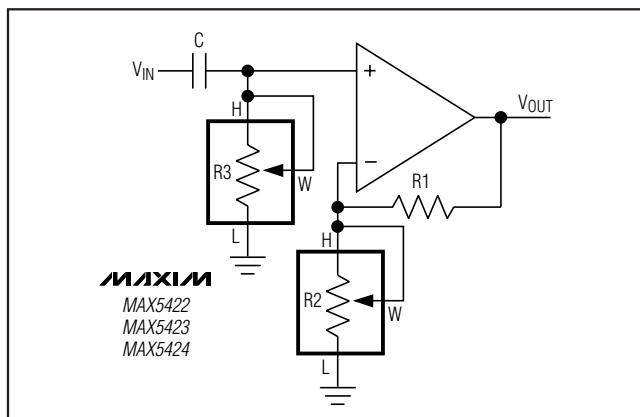


Figure 5. Programmable Filter

Adjustable Voltage Reference

Figure 6 shows the MAX5422/MAX5423/MAX5424 used as the feedback resistors in an adjustable voltage-reference application. Independently adjust the output voltage of the MAX6160 from 1.23V to $V_{IN} - 0.2V$ by changing the wiper position of the MAX5422/MAX5423/MAX5424.

Offset Voltage and Gain Adjustment

Connect the high and low terminals of one potentiometer of a MAX5422/MAX5423/MAX5424 between the NULL inputs of a MAX410 and the wiper to the op amp's positive supply to nullify the offset voltage over the operating temperature range. Install another MAX5422/MAX5423/MAX5424 potentiometer in the feedback path to adjust the gain of the MAX410 (see Figure 7).

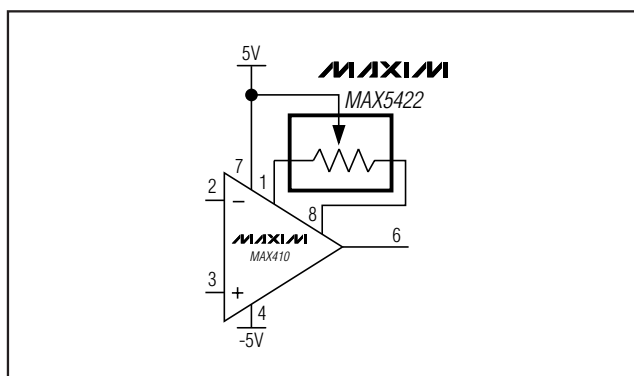


Figure 7. Offset Voltage Adjustment Circuit

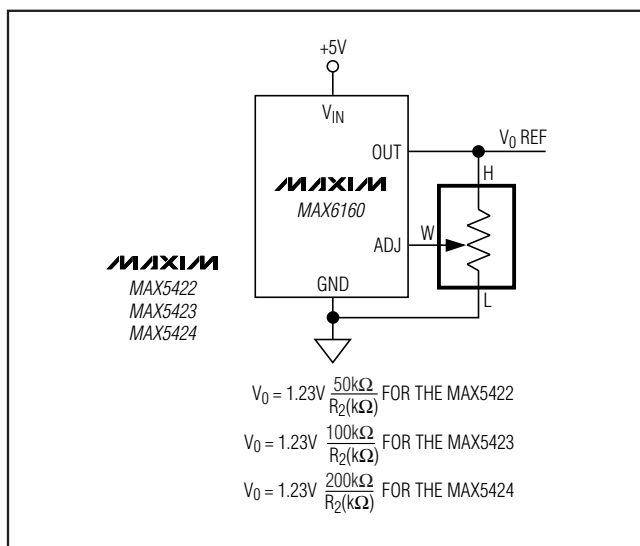


Figure 6. Adjustable Voltage Reference

Chip Information

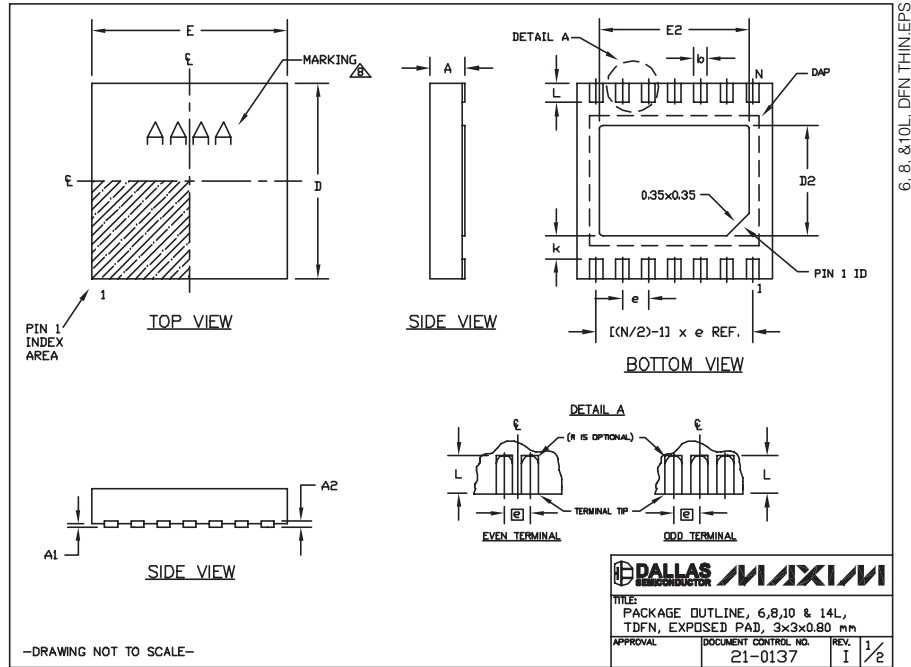
TRANSISTOR COUNT: 10,191

PROCESS: BiCMOS

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Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



COMMON DIMENSIONS		
SYMBOL	MIN.	MAX.
A	0.70	0.80
D	2.90	3.10
E	2.90	3.10
A1	0.00	0.05
L	0.20	0.40
k	0.25 MIN.	
A2	0.20 REF.	

PACKAGE VARIATIONS									
PKG. CODE	N	D2	E2	e	JEDEC SPEC	b	[(N/2)-1] x e		
T633-2	6	1.50±0.10	2.30±0.10	0.95 BSC	MO229 / WEEA	0.40±0.05	1.90 REF		
T833-2	8	1.50±0.10	2.30±0.10	0.65 BSC	MO229 / WEEC	0.30±0.05	1.95 REF		
T833-3	8	1.50±0.10	2.30±0.10	0.65 BSC	MO229 / WEEC	0.30±0.05	1.95 REF		
T1033-1	10	1.50±0.10	2.30±0.10	0.50 BSC	MO229 / WEED-3	0.25±0.05	2.00 REF		
T1033-2	10	1.50±0.10	2.30±0.10	0.50 BSC	MO229 / WEED-3	0.25±0.05	2.00 REF		
T1433-1	14	1.70±0.10	2.30±0.10	0.40 BSC	----	0.20±0.05	2.40 REF		
T1433-2	14	1.70±0.10	2.30±0.10	0.40 BSC	----	0.20±0.05	2.40 REF		

NOTES:
1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES.
2. COPLANARITY SHALL NOT EXCEED 0.08 mm.
3. WARPAGE SHALL NOT EXCEED 0.10 mm.
4. PACKAGE LENGTH/PACKAGE WIDTH ARE CONSIDERED AS SPECIAL CHARACTERISTIC(S).
5. DRAWING CONFORMS TO JEDEC MO229, EXCEPT DIMENSIONS "D2" AND "E2", AND T1433-1 & T1433-2.
6. "N" IS THE TOTAL NUMBER OF LEADS.
7. NUMBER OF LEADS SHOWN ARE FOR REFERENCE ONLY.
8. MARKING IS FOR PACKAGE ORIENTATION REFERENCE ONLY.

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